

M.Tech. Electronics & Communication Engineering (CBCS Pattern) Semester - II
PECS24C / PECS243 - Microwave Devices & Amplifier Design

P. Pages : 1

Time : Three Hours



GUG/S/23/11036

Max. Marks : 70

- Notes :
1. All questions carry marks as indicated.
 3. Answer **any five** questions.
 3. Assume suitable data wherever necessary.
 4. Illustrate your answers wherever necessary with the help of neat sketches.

1. a) Write any two limitations of conventional tubes at Microwave frequencies. 6
b) What are the modes of operation that result in microwave oscillations in a Gunn diode? Explain in detail. 8
2. a) Explain the principle of working of Travelling Wave Tube with neat sketches. 7
b) Draw the equivalent circuit of varactor diode and explain its operation. What are the applications of varactor diode? 7
3. a) Derive the S-matrix for directional coupler. 7
b) Explain how Manley-Rowe power relations are useful in the prediction of power gain possibility in a parametric amplifier. 7
4. a) With the help of Applegate diagram, explain the operation of a reflex klystron; show that the theoretical efficiency of reflex klystron is 27.78% 7
b) With the help of velocity diagram explain principle of two-cavity Klystron amplifier. 7
5. a) Draw the experimental setup for the measurement of impedance of discontinuity and explain. 7
b) Explain using suitable diagrams two methods of designing broad band amplifier. 7
6. a) Explain in detail Double ended diode mixer. What are mixer design considerations? 7
b) Design a low pass constant K filter using image parameter method. 7
7. a) Describe the characteristics of amplifier and Examine the transducer power gain, unilateral power gain, available power gain and operating power gain of a microwave amplifier using S parameters. 8
b) Compare the different types of mixers with its principle of operation. 6
8. a) Explain oscillator phase noise in detail. 7
b) Explain the oscillation mechanism and the electron trajectory concept of magnetron oscillator. 7
